# 2SC4808G

### Silicon NPN epitaxial planar type

For UHF band low-noise amplification

#### Features

- Low noise figure NF
- High forward transfer gain  $|S_{21e}|^2$
- High transition frequency  $f_T$
- SS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	15	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	10	V	
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	2	V	
Collector current	I <sub>C</sub>	80	mA	
Collector power dissipation	P <sub>C</sub>	125	mW	
Junction temperature	Tj	125	°C	
Storage temperature	T <sub>stg</sub>	-55 to +125	°C	

- Package
- Code
  - SSMini3-F3
- Marking Symbol: 3M
- Pin Name
  - 1. Base
  - 2. Emitter
  - 3. Collector

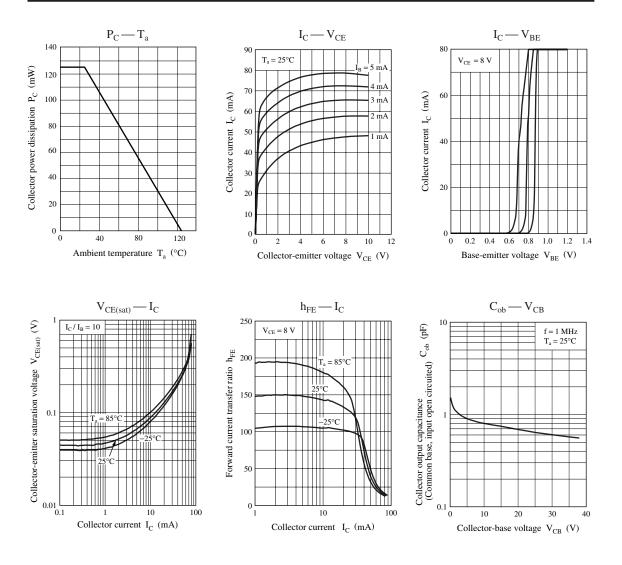
#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$	15			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{C} = 100 \ \mu A, I_{B} = 0$	10			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = 10 \text{ V}, I_E = 0$			1	μΑ
Emitter-base cutoff current (Collector open)	I <sub>EBO</sub>	$V_{EB} = 2 V, I_C = 0$			1	μΑ
Forward current transfer ratio *	h <sub>FE</sub>	$V_{CE} = 8 V, I_C = 20 mA$	50	150	300	
Transition frequency	f <sub>T</sub>	$V_{CE} = 8 \text{ V}, I_{C} = 15 \text{ mA}, f = 0.8 \text{ GHz}$	5	6		GHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		0.7	1.2	pF
(Common base, input open circuited)						
Forward transfer gain	$ S_{21e} ^2$	$V_{CE} = 8 \text{ V}, I_{C} = 15 \text{ mA}, f = 0.8 \text{ GHz}$	11	14		dB
Maximum unilateral power gain	G <sub>UM</sub>	$V_{CE} = 8 V, I_C = 15 mA, f = 0.8 GHz$		15		dB
Noise figure	NF	$V_{CE} = 8 V, I_C = 7 mA, f = 0.8 GHz$		1.3	2.0	dB

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Pulse measurement

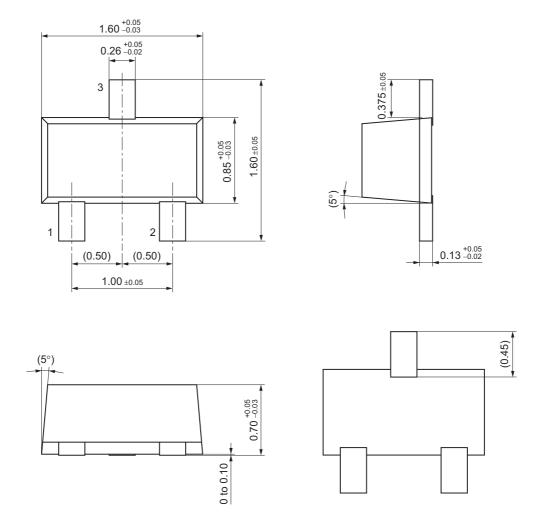
### Panasonic



### **Panasonic**

### SSMini3-F3

#### Unit: mm



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